



DMN6040SFDE

Product Summary

в	BVDSS	R _{DS(ON)} Max	Package	I _D Max T _A = +25°C
	60V	38mΩ @ V _{GS} = 10V	U-DFN2020-6	6.5A
	6U V	$47m\Omega @ V_{GS} = 4.5V$	(Type E)	5.2A

Description

This new generation MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- **Power Management Functions**

60V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test In Production
- 0.6mm Profile Ideal for Low-Profile Applications
- PCB Footprint of 4mm²
- Low On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts gualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

An Automotive-Compliant Part is Available Under Separate Datasheet (DMN6040SFDEQ)

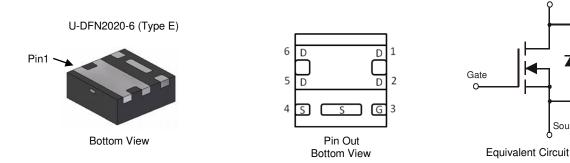
Mechanical Data

- Package: U-DFN2020-6
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

Drain

Source

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.0065 grams (Approximate)



Ordering Information (Note 4)

Part Number	Baakaga	Marking	Reel Size (inches)	Packing			
Part Number	Package	Marking	Reel Size (Inclies)	Qty.	Carrier		
DMN6040SFDE-7	U-DFN2020-6 (Type E)	N8	7	3,000	Reel		
DMN6040SFDE-13	U-DFN2020-6 (Type E)	N8	13	10,000	Reel		

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Notes:



Marking Information

Site 1:



N8 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2012		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	Z		Н	I	J	K	L	М	N	0	Р	R
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2:



N8 = Product Type Marking Code YWX = Date Code Marking

 $\begin{array}{l} Y = Y ear \ (ex: 1 = 2021) \\ W = Week \ (ex: a = Week \ 27; z \ Represents \ Week \ 52 \ and \ 53) \\ X = Internal \ Code \ (ex: U = Monday) \end{array}$

Date	Code	Key
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Year	2012		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	2		0	1	2	3	4	5	6	7	8	9
Week	1-26			27-52				53				
Code	A-Z				a-z				Z			
			-					-			_	
Internal Code	Su	ın	Mor	n	Tue	1	Wed	Thu	1	Fri		Sat
Code	1	-	U		V		W	Х		Y		Z

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit		
Drain-Source Voltage		V _{DSS}	60	V		
Gate-Source Voltage		Vgss	±20	V		
	Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$		ID	5.3 4.1	А	
Continuous Drain Current (Note 6) V _{GS} = 10V	t < 10s	TA = +25°C T _A = +70°C	lo	6.5 5.1	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	%)	•	Ідм	30	А	
Maximum Body Diode Continuous Current		ls	2.5	А		
Avalanche Current (Note 7) L = 0.1mH		I _{AS}	14.2	А		
Avalanche Energy (Note 7) L = 0.1mH		Eas	10	mJ		

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	0.66	W
Total Fower Dissipation (Note 5)	TA = +70°C	PD	0.42	vv
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	ReJA	189	°C/W
Thermal Resistance, Junction to Amblent (Note 5)	t < 10s	ΠθJA	132	0/11
Total Power Dissipation (Note 6)	$T_A = +25^{\circ}C$	T _A = +25°C		W
Total Fower Dissipation (Note 0)	$T_A = +70^{\circ}C$	PD	1.31	vv
Thermal Resistance Junction to Ambient (Note 6)	Steady State	D	61	
Thermal Resistance, Junction to Ambient (Note 6)	RθJA	43	°C/W	
Thermal Resistance, Junction to Case (Note 6)	Rejc	9.3		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

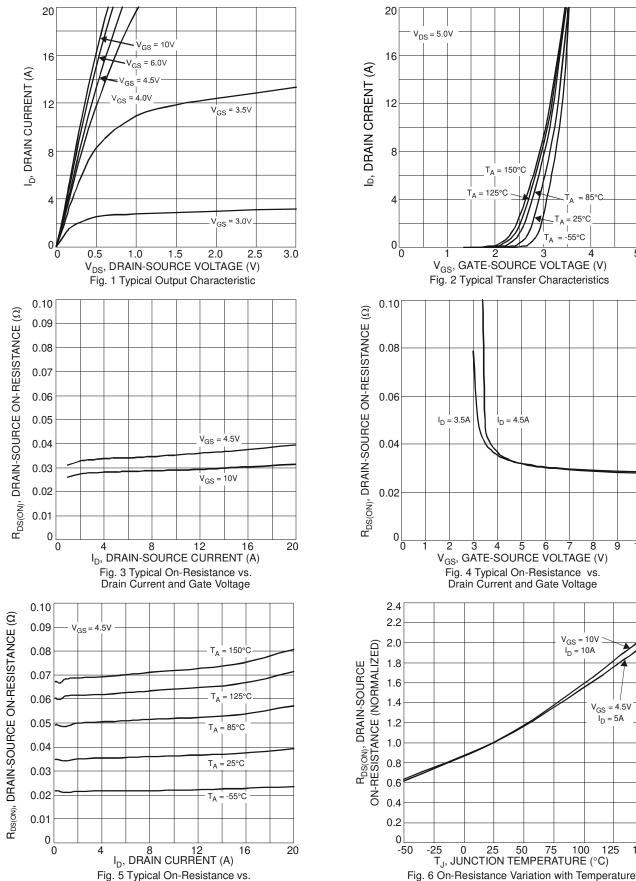


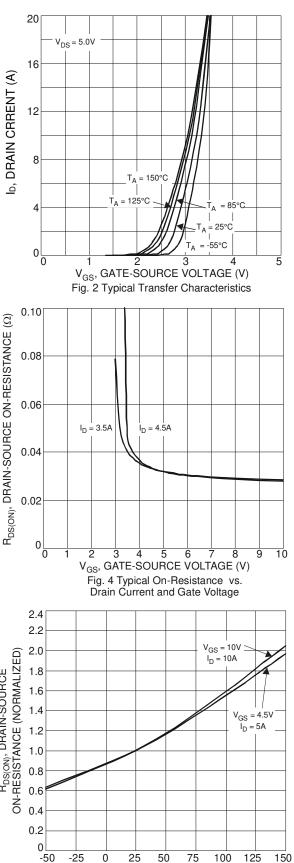
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)				-		
Drain-Source Breakdown Voltage	BVDSS	60		—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_	—	100	nA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	VGS(TH)	1	—	3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Besistance	Deserve	_	30	38		VGS = 10V, ID = 4.3A
Static Drain-Source On-Resistance	RDS(ON)	_	35	47	mΩ	VGS = 4.5V, ID = 4A
Forward Transfer Admittance	Y _{fs}	_	4.5	_	S	$V_{DS} = 10V, I_D = 4.3A$
Diode Forward Voltage	Vsd	_	0.7	1.2	V	$V_{GS} = 0V$, $I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		1287	_		
Output Capacitance	Coss	_	57	_	pF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	44	_		
Gate Resistance	Rg		1.2	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	_	22.4	_		
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	10.4	_	nC	
Gate-Source Charge	Qgs	_	4.9	_	no	$V_{DS} = 30V, I_D = 4.3A$
Gate-Drain Charge	Q _{gd}	_	3.0	_		
Turn-On Delay Time	tD(ON)		6.6	_		
Turn-On Rise Time	tR		8.1	_		$V_{GS} = 10V, V_{DD} = 30V, R_{G} = 6\Omega,$
Turn-Off Delay Time	tD(OFF)		20.1	_	ns	I _D = 4.3A
Turn-Off Fall Time	tF	_	4.0	—	1	
Body Diode Reverse Recovery Time	t _{RR}	_	18		ns	I _S = 4.3A, dl/dt = 100A/µs
Body Diode Reverse Recovery Charge	Qrr	_	11.9		nC	Is = 4.3A, dl/dt = 100A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



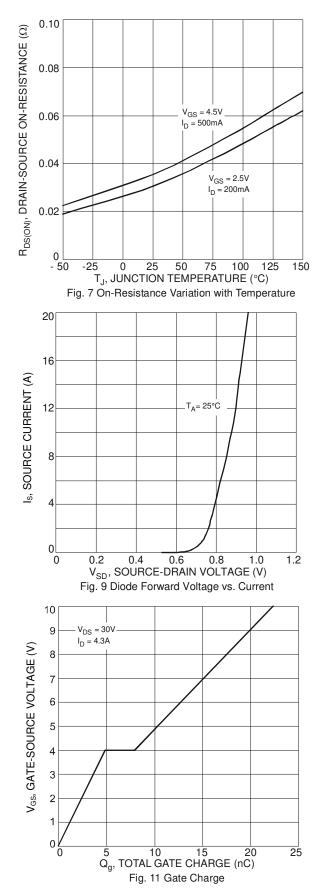


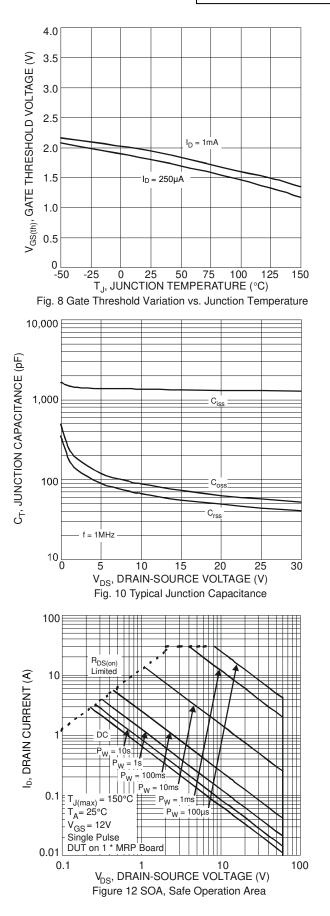


TJ, JUNCTION TEMPERATURE (°C)

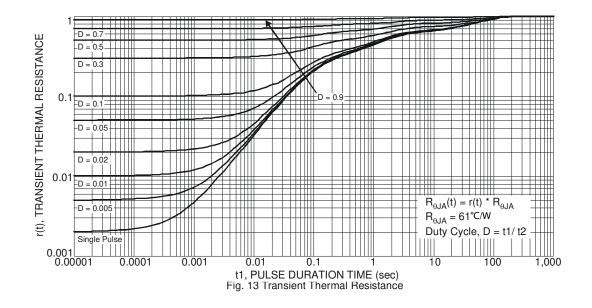
Drain Current and Temperature







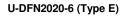


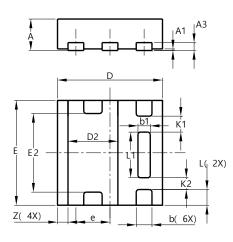




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

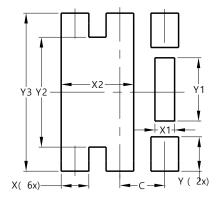




U-DFN2020-6							
		ype E					
Dim	Min	Max	Тур				
Α	0.57	0.63	0.60				
A1	0	0.05	0.03				
A3		-	0.15				
b	0.25	0.35	0.30				
b1	0.185	0.285	0.235				
D	1.95	2.05	2.00				
D2	0.85	1.05	0.95				
Е	1.95	2.05	2.00				
E2	1.40	1.60	1.50				
e	1	-	0.65				
1	0.25	0.35	0.30				
L1	0.82	0.92	0.87				
K1		-	0.305				
K2	_	_	0.225				
Z	-	_	0.20				
All	Dimen	sions	in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2020-6 (Type E)

Dimensions	Value
Dimensions	(in mm)
С	0.650
Х	0.400
X1	0.285
X2	1.050
Y	0.500
Y1	0.920
Y2	1.600
Y3	2.300



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